## V10D100C-M3, V10D100CHM3

Vishay General Semiconductor

## **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low V<sub>F</sub> = 0.48 V at I<sub>F</sub> = 2.5 A



## V10D100C



| PRIMARY CHARACTERISTICS                  |                     |  |  |  |
|--|---------------------|--|--|--|
| I <sub>F(AV)</sub>                       | 2 x 5.0 A           |  |  |  |
| V <sub>RRM</sub>                         | 100 V               |  |  |  |
| I <sub>FSM</sub>                         | 100 A               |  |  |  |
| $V_F$ at $I_F$ = 5.0 A ( $T_A$ = 125 °C) | 0.60 V              |  |  |  |
| T <sub>J</sub> max.                      | 150 °C              |  |  |  |
| Package                                  | TO-263AC (SMPD)     |  |  |  |
| Diode variations                         | Dual common cathode |  |  |  |

#### FEATURES

- Trench MOS Schottky technology generation 2
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  Automotive ordering code: base P/NHM3
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

#### **MECHANICAL DATA**

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** As marked

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)               |            |                                   |             |      |  |
|--|------------|-----------------------------------|-------------|------|--|
| PARAMETER  |            | SYMBOL                            | V10D100C    | UNIT |  |
| Maximum repetitive peak reverse voltage  |            | V <sub>RRM</sub>                  | 100         | V    |  |
| Maximum average forward rectified current (fig. 1)                                   | per device | I <sub>F(AV)</sub>                | 10          | А    |  |
|  | per diode  |                                   | 5           | A    |  |
| Maximum DC reverse voltage   |            | V <sub>DC</sub>                   | 160         | V    |  |
| Peak forward surge current 10 ms single half sine-wave<br>superimposed on rated load |            | I <sub>FSM</sub>                  | 100         | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )                                       |            | dV/dt                             | 10 000      | V/µs |  |
| Operating junction and storage temperature range                                     |            | T <sub>J</sub> , T <sub>STG</sub> | -40 to +150 | °C   |  |

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ROHS COMPLIANT

HALOGEN

FREE

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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \degree C$ unless otherwise noted) |                        |                               |                               |      |      |      |  |
|--|------------------------|-------------------------------|-------------------------------|------|------|------|--|
| PARAMETER  | TEST CO                | TEST CONDITIONS SYMBOL        |                               | TYP. | MAX. | UNIT |  |
| Instantaneous forward voltage  | I <sub>F</sub> = 2.5 A | $T_{A} = 25 ^{\circ}\text{C}$ | V <sub>F</sub> <sup>(1)</sup> | 0.55 | -    | V    |  |
|  | I <sub>F</sub> = 5.0 A |                               |                               | 0.67 | 0.75 |      |  |
|  | I <sub>F</sub> = 2.5 A | T <sub>A</sub> = 125 °C       |                               | 0.48 | -    |      |  |
|  | I <sub>F</sub> = 5.0 A |                               |                               | 0.60 | 0.68 |      |  |
| Reverse current at rated V <sub>R</sub> per diode                                | V <sub>B</sub> = 70 V  | T <sub>A</sub> = 25 °C        | I <sub>R</sub> <sup>(2)</sup> | 2.3  | -    | μA   |  |
|  | v <sub>R</sub> = 70 v  | T <sub>A</sub> = 125 °C       |                               | 2.3  | -    | mA   |  |
|  | V <sub>B</sub> = 100 V | T <sub>A</sub> = 25 °C        |                               | -    | 500  | μA   |  |
|  | v <sub>R</sub> = 100 v | T <sub>A</sub> = 125 °C       |                               | 7    | 20   | mA   |  |

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  5 ms

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |            |                                    |          |      |  |
|--|------------|------------------------------------|----------|------|--|
| PARAMETER  |            | SYMBOL                             | V10D100C | UNIT |  |
| Typical thermal resistance   | per diode  | $R_{	ext{	heta}JC}$                | 3.5      |      |  |
|  | per device |                                    | 2.5      | °C/W |  |
|  | per device | R <sub>0JA</sub> <sup>(1)(2)</sup> | 48       |      |  |

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{0JA}$  - junction-to-mount

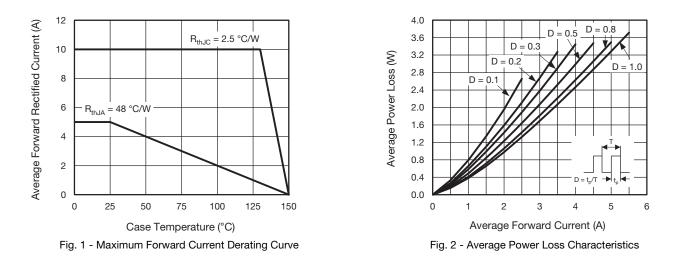
<sup>(2)</sup> Free air, without heatsink

| ORDERING INFORMATION (Example) |                   |                    |              |               |                                    |
|--------------------------------|-------------------|--------------------|--------------|---------------|------------------------------------|
| PACKAGE                        | PREFERRED P/N     | UNIT WEIGHT<br>(g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |
| TO-263AC (SMPD)                | V10D100C-M3/I     | 0.55               | I            | 2000/reel     | 13" diameter plastic tape and reel |
| TO-263AC (SMPD)                | V10D100CHM3/I (1) | 0.55               | I            | 2000/reel     | 13" diameter plastic tape and reel |

Note

(1) AEC-Q101 qualified

#### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)



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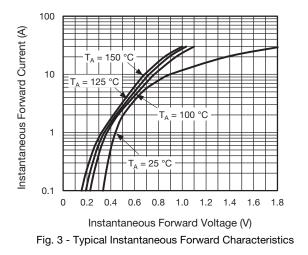
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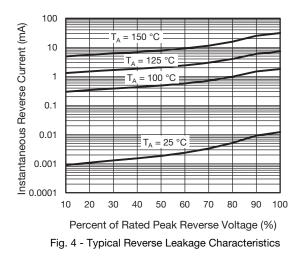
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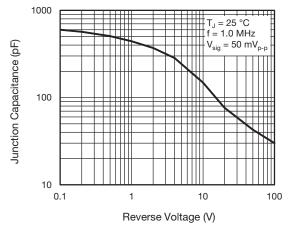
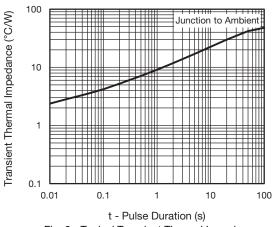
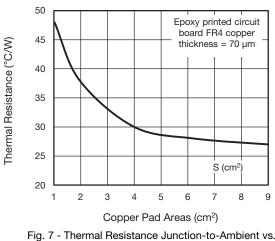


Fig. 5 - Typical Junction Capacitance





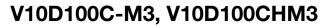


Copper Pad Areas

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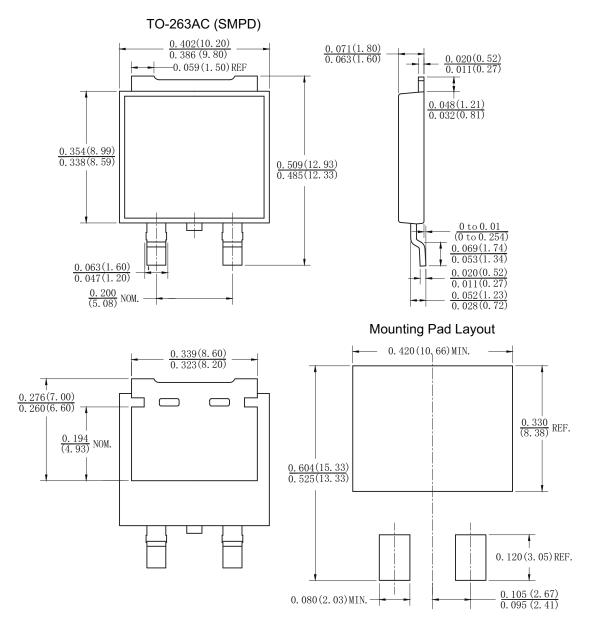


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#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

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